

AS-MLV-P2

Air Quality Sensor

General Description

The **ams** AS-MLV-P2 is a MOS (metal oxide semiconductor) based gas sensor component. It was specifically designed for a broad detection of reducing gases such as VOCs (volatile organic compounds) and CO (carbon monoxide) associated with bad air quality. The AS-MLV-P2 sensor component is a MEMS (micro electromechanical system) device using silicon wafer technology.

Ordering Information and Content Guide appear at end of datasheet.

Key Benefits & Features

The benefits and features of AS-MLV-P2, Air Quality Sensor are listed below:

Figure 1: Added Value of Using AS-MLV-P2 Sensor

Benefits	Features
High sensitivity to volatile organic compounds (VOCs)	Limit of detection in a low ppm range
Very low power consumption	• 34 mW at 300°C
Maintenance free	• 10 year lifetime
Reflow capable	Surface Mount Package

Applications

- · Indoor air monitor
- Kitchen hood
- Weather stations
- Smart home
- Internet of Things (IoT)



Pin Assignment

Figure 2: Pin Diagram

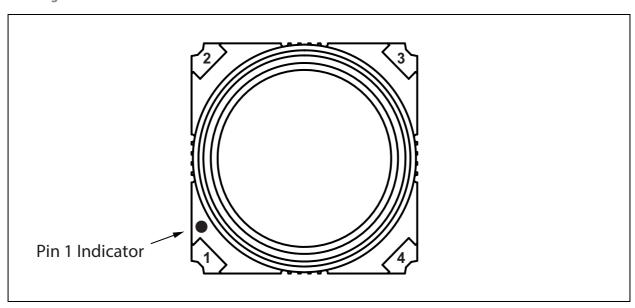


Figure 3: Pin Description

Pin Number	Pin Name	Description
1	RS1	Sensor electrode 1
2	RH1	Heater 1
3	RS2	Sensor electrode 2
4	RH2	Heater 2

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Environmental Specifications

The sensor element characteristics are valid under the following environmental conditions:

Figure 4: Environmental Operating Conditions

Description	Value		
Ambient 0	perating Range		
Temperature range	0°C to 50°C		
Humidity range (relative humidity, non-condensing)	5% to 95%		
Ambient	Storage Range		
Storage temperature range	-40°C to 85°C		
Storage humidity range (relative humidity, non-condensing)	5% to 95%		
Air Flow			
Experienced air velocity	0m/s to 4m/s		

Note(s):

1. The sensor must be kept separate from all sourced of silicone contamination to fulfill the functional and lifetime requirements.

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Electrical Characteristics

The sensor elements operate at an elevated temperature. The elevated temperature is realized by means of the Pt heater which is implemented within the silicon nitride membrane. The recommended operating temperature for the AS-MLV-P2 is 300°C, which is equivalent to an applied power of approx. 34mW at room temperature.

Figure 5: Electrical Characteristics

Description	Value			
Resistance Values				
Sensor resistance range	$3k\Omega$ to $3M\Omega$			
Typical baseline in ambient air	50kΩ to 500kΩ			
Heater resistance (2)	$150\Omega \pm 30\Omega$ at 300° C			
Absolute Maxim	num Supply Ratings			
Power supply	50mW (very short time range)			
Heater current	25mA			
Heater Voltage	3.0 V			
Lifetime R	Requirements			
Expected lifetime (1)	10 years			
With a minimum of	85.000 hours			
On/off cycles	20.000 times			
Sensor Eler	nent Response			
Response from	10%			
To its final value	90%			
For 0 - 20 ppm CO within	<10sec			
Sensor Element Recovery				
Response from	10%			
To its final value	90%			
Back from 20 – 0 ppm CO	<1min			

Note(s):

- 1. This lifetime can only be reached with respect to the recommended operation of the sensor. Especially the maximum ratings during operation have to be followed carefully. With this background, the AS-MLV-P2 is maintenance free and shall require no replacement during specified lifetime.
- 2. Pt heater element operates at 300°C

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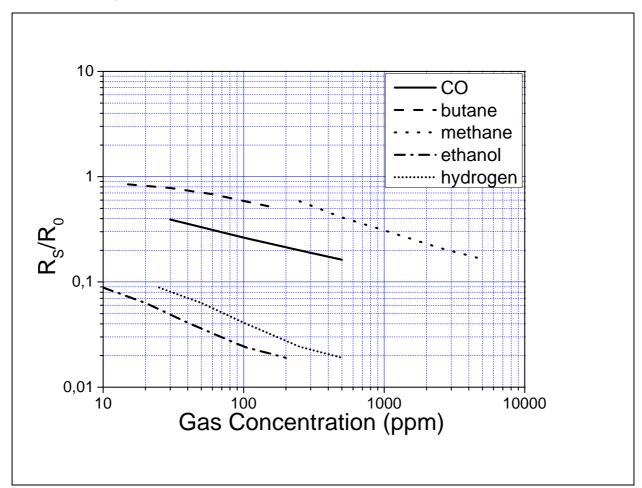
Detailed Description

AS-MLV-P2 heater and inter-digital electrode structures use Platinum and are implemented in an approximately one micrometer-thin silicon nitride membrane to achieve ultimate stability and lowest possible power consumption. A highly sensitive and long-term stable polycrystalline tin dioxide-based sensitive material is deposited on the inter-digital electrodes. At an elevated operation temperature of approx. 300°C, this catalytically active material shows a gas concentration dependent resistance change.

Sensing Properties

The AS-MLV-P2 sensor component shows a strong sensitivity to a wide range of reducing gases as can be seen in Figure 6. Please note that those results may vary due to different environmental conditions.

Figure 6: Sensor Sensitivity



Sensor Sensitivity: Sensitivities for various gas concentrations, this graph shall just give an indication and can vary slightly from sensor to sensor.

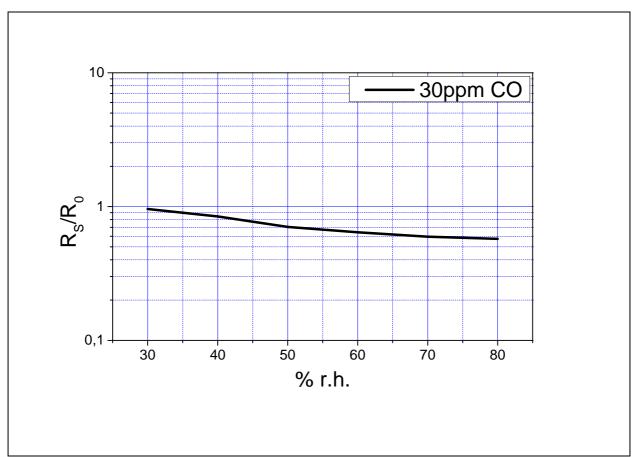
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Cross Sensitivities

Due to the basic operation principle of MOS gas sensors, the AS-MLV-P2 sensor component does have a cross sensitivity to humidity changes. This effect provides additional information and widens the application range for the sensor. This feature especially supports applications in environments where the detection of significant humidity changes is supporting the functionality, such as bathroom and kitchen environments. Figure 7 shows the dependency of humidity using the example of CO signals to get a visualized feeling for the effect. Please note that this dataset is just meant to be an example and the values may vary from sensor to sensor.

Figure 7: Cross Sensitivity of Humidity for CO



Cross Sensitivity of Humidity for CO: Cross sensitivity of humidity for the example of CO. This data is just meant to be a visualization of the influence of humidity and will vary slightly from sensor to sensor.

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Application Information

Due to the characteristics of the sensor, there are some issues to be taken care of while implementing. The operation temperature of the sensor has to be kept constant; therefore the circuit on heater site shall have the possibility to be regulated. The critical issue of the sensor resistance is the wide range of values which has to be covered during operation.

All following circuits are meant to be examples which have to be adapted carefully to the different applications.

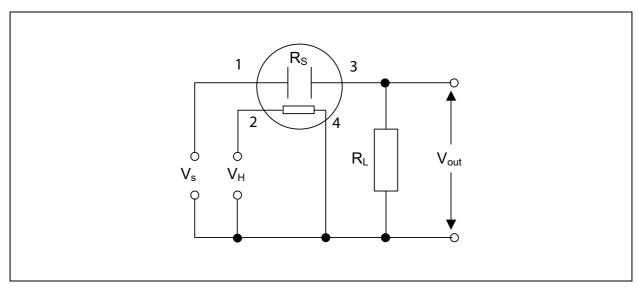
Sensor Resistance

The sensitive layer can change its resistance over several orders of magnitude, depending on the production and gas exposition. The electrical power dissipated in the sensitive layer must be limited and must not exceed 2mA. This power shall also avoid performing high changes over short time. Because of this issue a measuring range shifting realized with series resistors will have an effect to the sensor signal and should be avoided.

As a suggestion we measure the sensor resistance with a simple voltage divider as shown in Figure 8. V_H determines the heater voltage and therefore the operation temperature of the sensor. This regulation is described in a later chapter. Here we focus on the sensor resistance measuring. To meet the described specification a value of 10kOhm or 100kOhm for the load resistor (R_L) and a Voltage of 5V for V_S is a good starting point for a broad range of the sensor applications. A high precision noise free voltage source is recommended for generating V_S . R_S and R_L form a voltage divider, which can be used to calculate R_S (see EQ 1).

(EQ1)
$$R_S = R_L \left(\frac{V_S}{V_{out}} - 1 \right)$$

Figure 8:
A Basic Measurement Circuit for the Sensor Resistance



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The resolution of the measurement of R_S is recommended to be better or equal to 1% of the actual reading. This allows making use of the full performance of the sensor. The requirements for the A/D conversion of the output voltage V_{out} is described in the following section.

The input impedance of the A/D converter should be high enough not to influence the level of the voltage divider, a ration of at least 10 between input impedance and values of R_{S} and/or R_{L} is recommended.

Averaging A/D conversion procedures are recommended in order to suppress fast resistance changes from the sensitive layer (resistive noise and change of the resistance due to chemical influences).

In order to achieve 1% of precision of the read-out of R_S , the A/D conversion of V_{out} needs lower resolution, if sensor- and load resistor match. A larger difference between R_S and R_L requires a higher resolution of the A/D conversion. The following figure gives a few examples for $V_S = 5V$.

Figure 9: Examples for Readout of R_S with 1% Resolution (V_S=5V)

R _S [Ohm]	R _L [Ohm]	V _{out} [V]	A/D Voltage Step for 1% Resolution
100	10k	4.95	0.5mV
1k	10k	4.5454	4.1mV
10k	10k	2.5	12.4mV
100k	10k	0.4545	4.1mV
1M	10k	0.0495	0.5mV
1k	100k	4.95	0.5mV
10k	100k	4.5454	4.1mV
100k	100k	2.5	12.4mV
1M	100k	0.4545	4.1mV

Examples for Readout of R_S with 1% Resolution: The series resistor R_L has also the functionality to limit the power dissipated to the sensitive layer.

If the A/D conversion is single ended (common ground) it might be useful to change the sequence of load resistor and sensor resistor in the voltage divider. This enables to increase the resolution by using a lower reference voltage for the A/D conversion.

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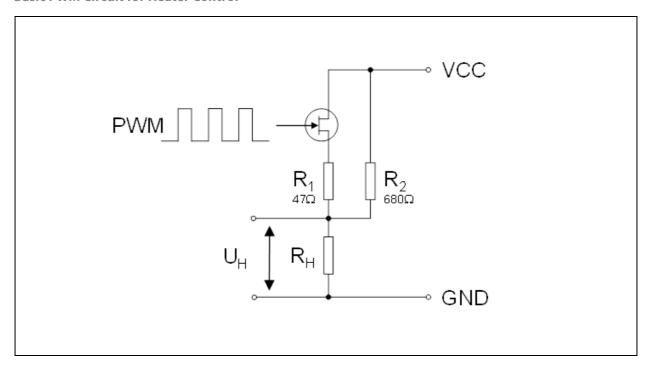
A constant current source can also be used to read-out the sensitive layer. In this case the electrical power dissipated in the sensitive layer must be limited and must not exceed 1mW for all values of R_{S} .

Heater Control

To solve the application the sensor needs a certain temperature, the operation point. This temperature correlates with the heater resistance of the sensor module. The heater resistance and its TCR varies with production and the sensor temperature should be adjusted by applying a calibration step up front. In this calibration step the characteristic of the correlation of temperature and heater power is used. For iAQ applications the dependency for the operation temperature of ~300°C is 34mW @ 23°C \pm 2°C. The measured heater resistance value with this applied conditions is the set-point which will be important for the further operation.

Variation of ambient temperature may have an influence in the sensor temperature and its heater resistance. The chosen circuit shall be adjustable and should keep the heater resistance constant at the desired set-point. This can be solved by a basic PWM circuit shown in Figure 10.

Figure 10:
Basic PWM Circuit for Heater Control



Basic PWM Circuit for Heater Control: A typically heater driver circuit, R1 is the current limit resistor, R2 is needed as a bypass resistor

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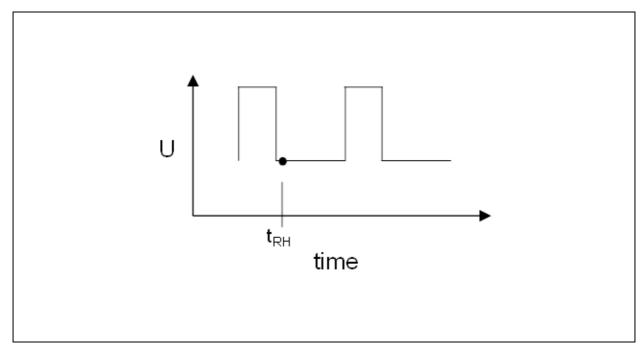
To use the example a p-channel MOSFET is mandatory; using an n-channel will need a change of the overall circuit design. In this case the Voltage VCC is 5V with a max ripple of 20mV, but the circuit is also valid for 3.3V. The circuit should be designed to achieve a PWM of 30-60% depending on heater set-point. This range gives the security that all specified environmental temperature ranges can be compensated.

The heater resistance should be measured at the beginning of the low phase indicated as T_{RH} in the drawing Figure 11. The Voltage drop UH is measured and Rh can be calculated as shown in EQ 2.

$$\text{(EQ2)} \qquad \text{R}_{H} = \frac{\text{U}_{H} \cdot \text{R}_{2}}{\text{VCC} - \text{U}_{H}}$$

Please note that this circuit are just mend to be an example and each circuit which can fulfill the conditions and respects the absolute maximum ratings of the sensor can be used.

Figure 11: Example of PWM Cycle with Measurement Point



The heater can also be controlled by a DAC controlled circuit with a voltage divider.

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Heater Calibration

As mentioned in the previous chapter the each sensor has its own set-point at the operation temperature. This set-point can be determined by a previous calibration step. This means that the AS-MLV-P2 is started at room temperature (23°C \pm 3°C) and powered with 34mW. With these conditions the heater resistance is measured and stored into the EEPROM. This heater resistance is the certain set-point which is kept constant with the regulating PWM during operation.

General Characteristics

The sensor has some native characteristics which should be considered in the application development.

Burn-In Behavior

Once in lifetime the sensor performs a special burn in behavior, this curve is characterized in three phases which are described with the following figure.

Figure 12: **Burn-In of Sensor**

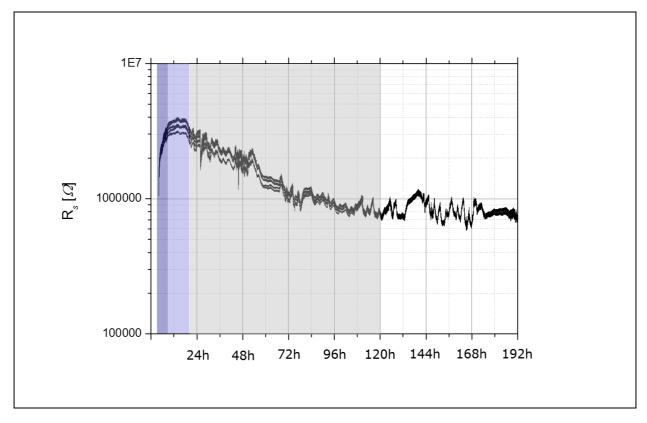
Description		Duration
Phase 1	Fast increase of the sensor resistance	~ 10 hours
Phase 2	Plateau with nearly stable baseline	~ 12 hours
Phase 3	Long drift like decrease of the sensor resistance	> 4 days

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A characteristic example is shown in Figure 13. This behavior is caused due to manufacturing issues and is mandatory. After once following this issue it will never appear again. During the burn in phase the resistance range can be exceeded considerably.

Figure 13: Characteristic Resistance Curve during Burn-In



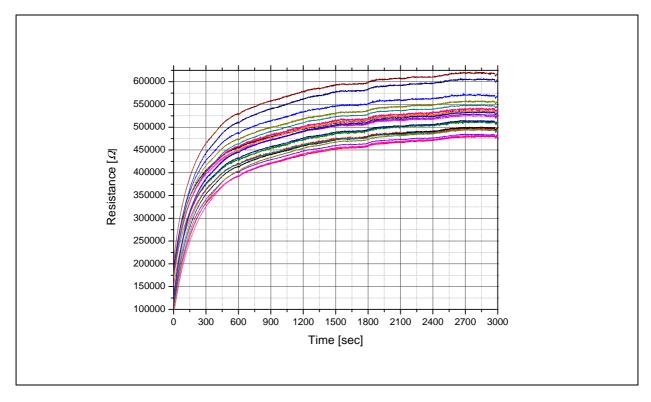
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Run-In

Each time after powering the sensor, the baseline of the sensitive layer performs a small run in phase. The curve is characterized with a steady increasing resistance. The length of this phase is depending on the sensors history. The longer the sensor was unpowered the longer the run in phase will take. The standard duration is approx. 3-5 minutes.

Figure 14: Run-In Phase of Sensor

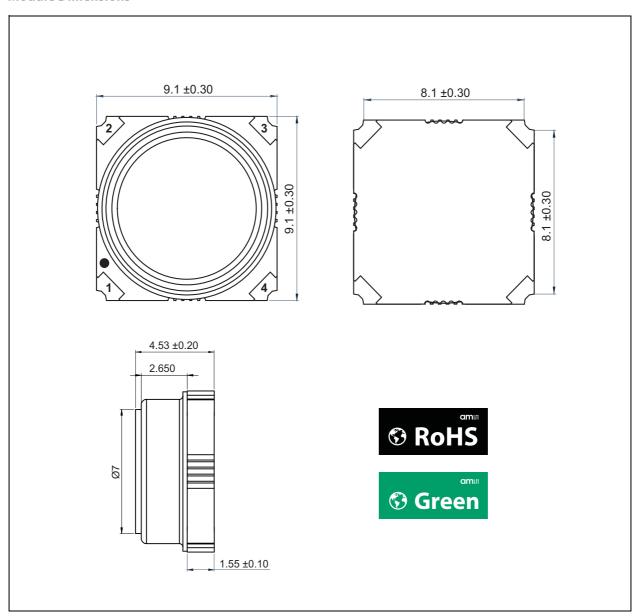


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Mechanical Information

Figure 15: Module Dimensions



Note(s):

1. All Dimensions are in millimeters.

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Figure 16: Module Markings

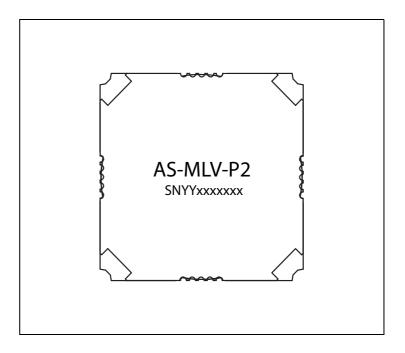


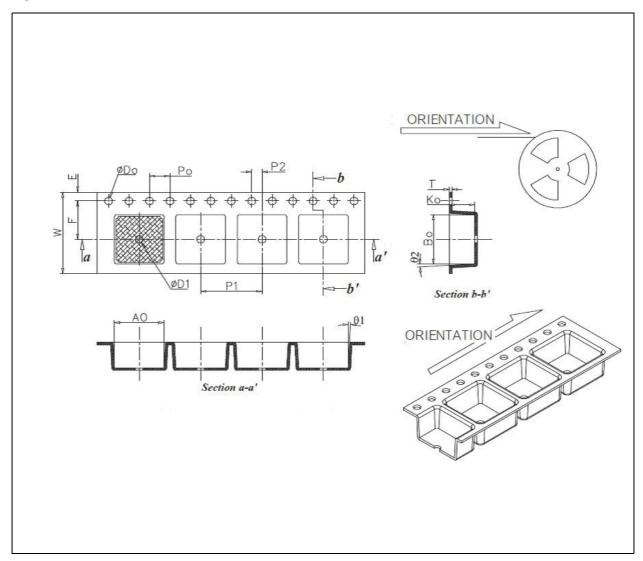
Figure 17: Module and Marking Elements

Item	Description
PCB Material	FR4 with gold surface (7μm Ni / 3μm Au)
Connector	Edge connector
Marking PIN1	White mark
Label	Laser mark AS-MLV-P2
Product name (first row)	AS-MLV-P2
	SNYYxxxxxx
Serial number (second row)	YY → two digits production year
	xxxxxxx → 7 digits running number

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Figure 18: Tape and Reel Information



Description	Items	Symbol	Value	Unit	Tolerance
Pocket	Length	Ao	9.70	- mm	±0.10
	Width	Во	9.70		
	Depth	Ко	5.00		
	Pitch	P1	12.00		
	Angle	θ1	3	Degree	Max.
	Angle	θ2	3	Degree	ividX.

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Description	Items	Symbol	Value	Unit	Tolerance
	Diameter	ΘD0	1.50		+0.10
	Diameter	ΘD1	1.50		-0.00
Perforation	Pitch	P0	4.00	mm	±0.10
	Pitch	P2	2.00		
	Position	E	1.75		
Distance between center line	Width	F	7.50		
	Туре	Ec	hips		
Carrier tape material	Width	W	16.00		±0.30
	Thickness	T	0.50	mm	±0.05
Requirement/ Notice	Camber 250mm. Should be less than 1.00mm by Camber gauge. Must conform to E.I.A. Standard.				

Note(s):

- 1. All dimensions are in millimeters unless otherwise stated.
- 2. Unspecified dimension tolerance should be $\pm 0.10 \text{mm}.$
- 3. Cumulative tolerance of 10 sprocket holes is ± 0.20 mm.

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Soldering Information

Handling

The AS-MLV-P2 should be handled carefully, shear stress should be avoided. The sensor is protected against particles and liquids by a membrane. This membrane shall not be removed or touched.

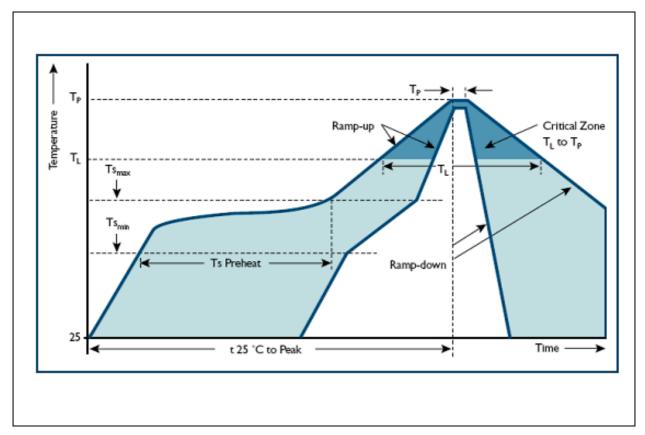
Soldering Instructions

The AS-MLV-P2 can be soldered in standard reflow soldering ovens. The reflow oven shall be purged with clean air. Other gases must be avoided. For the lead free reflow process a standard process IPC/JEDEC J-STD-020 with peak temperature up to maximum 230°C on surface is suggested. See Figure 19 for more detailed description.

Note(s): The device shall be kept clear of liquids; therefore a PCB washing process must be avoided in any case.

For manual soldering: contact must be limited to 5 seconds at a maximum temperature of 350°C.

Figure 19: Solder Reflow Graph



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Ordering & Contact Information

Figure 20: **Ordering Information**

Ordering Code	Marking	Delivery Form	Delivery Quantity
AS-MLV-P2	AS-MLV-P2	Tape & Reel	900

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Document Status

Document Status	Product Status	Definition
Product Preview	Pre-Development	Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice
Preliminary Datasheet	Pre-Production	Information in this datasheet is based on products in the design, validation or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice
Datasheet	Production	Information in this datasheet is based on products in ramp-up to full production or full production which conform to specifications in accordance with the terms of ams AG standard warranty as given in the General Terms of Trade
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Revision Information

Changes from 1-00 (2015-Jul-10) to current revision 1-01 (2015-Oct-12)	Page
Updated Figure 3	2
Updated EQ1	7
Updated Figure 8	7

Note(s):

- 1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
- $2. \, Correction \, of \, typographical \, errors \, is \, not \, explicitly \, mentioned.$

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